

## Quad Channel Monolithic Power Stage

### DESCRIPTION

The SiP2204 is a quad channel, fully-integrated monolithic power stage optimized for multi-phase synchronous buck applications. The part has very fast propagation to enable switching frequencies of up to 10 MHz/channel and offers a high power density design for use in applications such as envelope tracking power supplies for RF power amplifiers used in next generation 4G base stations.

Packaged in QFN32 5 x 5, SiP2204 supports input voltages up to 24 V and delivers 500 mA continuous current for each channel.

The SiP2204 incorporates four independent MOSFET gate driver ICs that work with both 3.3 V and 5 V PWM inputs.

### FEATURES

- QFN32 5 x 5 package
- Power stage input up to 24 V
- 500 mA per channel continuous current
- 2 A per channel peak current capability
- High frequency operation beyond 5 MHz
- 3.3 V and 5 V PWM logic
- Low PWM propagation delay (typical 13 ns)
- Enable feature to put the output at high impedance when disabled
- Junction temperature: -40 °C to +125 °C

### APPLICATIONS

- Envelope tracking (ET) supplies for RF power amplifiers (LDMOS, GaAs FET, GaAs HBT or GaN based)
- Synchronous buck converters

### TYPICAL APPLICATION CIRCUIT

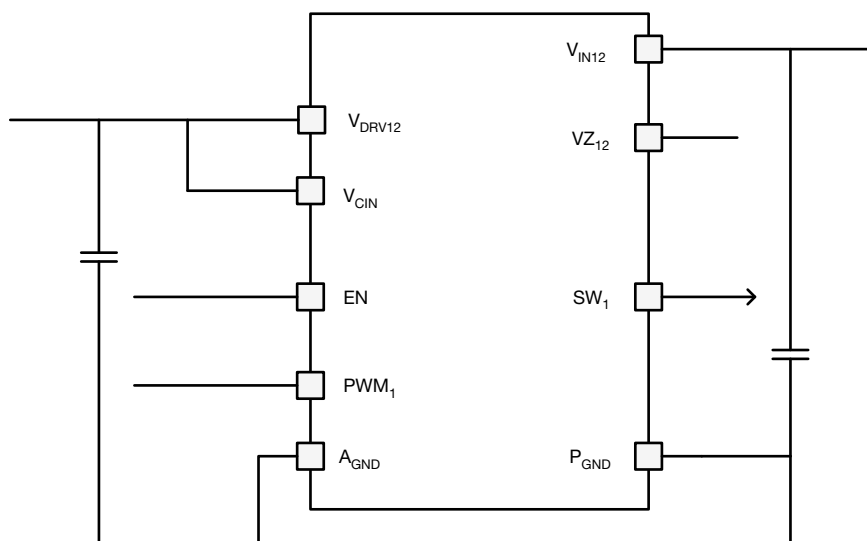
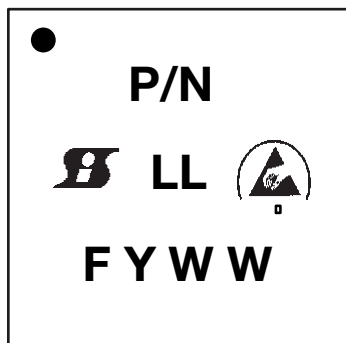


Fig. 1 - Typical Application Circuit for SiP2204  
(channel 1 shown)

**PART MARKING**


● = pin 1 indicator

P/N = part number code

 = Siliconix logo

 = ESD symbol

F = assembly factory code

Y = year code

WW = week code

LL = lot code

**ABSOLUTE MAXIMUM RATINGS**

| ELECTRICAL PARAMETER                                   | CONDITIONS                        | LIMIT                                            | UNIT |
|--------------------------------------------------------|-----------------------------------|--------------------------------------------------|------|
| Input voltage                                          | $V_{INX}$                         | -0.3 to +26                                      | V    |
| Control logic supply voltage                           | $V_{CIN}$                         | -0.3 to +6                                       |      |
| Low-side driver supply voltage                         | $V_{DRVX}$                        | -0.3 to +6                                       |      |
| Switch node (DC voltage)                               | $SW_X$                            | -0.3 to +26                                      |      |
| Switch node (AC voltage) <sup>(1)</sup>                |                                   | 29                                               |      |
| High-side regulator output monitor voltage             | $V_{ZX}$                          | $(V_{INX} - 6)$ to $V_{INX}$ and $V_{ZX} > -0.3$ |      |
| All logic inputs and outputs (PWM <sub>X</sub> and EN) |                                   | -0.3 to $V_{CIN} + 0.3$                          |      |
| Max. operating junction temperature                    | $T_J$                             | 150                                              | °C   |
| Ambient temperature                                    | $T_A$                             | -40 to +125                                      |      |
| Storage temperature                                    | $T_{stg}$                         | -65 to +150                                      |      |
| Electrostatic discharge protection                     | Human body model, JESD22-A114     | 3000                                             | V    |
|                                                        | Charged device model, JESD22-C101 | 1000                                             |      |

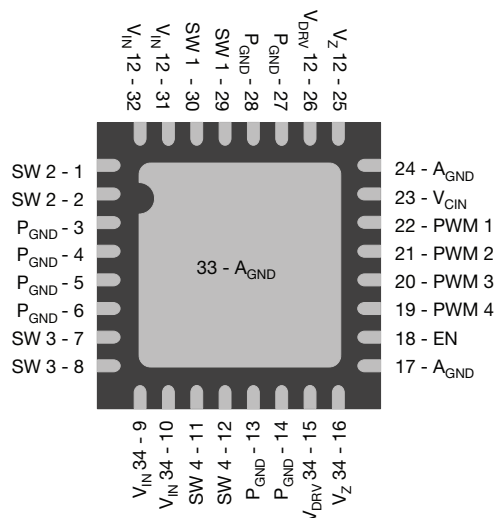
**Notes**

- Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability
- <sup>(1)</sup> The specification values indicated “AC” is  $SW_X$  to  $P_{GND}$ , 29 V (< 50 ns), max.

**RECOMMENDED OPERATING RANGE**

| ELECTRICAL PARAMETER                          | MINIMUM | TYPICAL | MAXIMUM | UNIT |
|-----------------------------------------------|---------|---------|---------|------|
| Input voltage ( $V_{INX}$ )                   | 10      | -       | 24      | V    |
| Low-side driver supply voltage ( $V_{DRVX}$ ) | 4.5     | 5       | 5.5     |      |
| Control logic supply voltage ( $V_{CIN}$ )    | 4.5     | 5       | 5.5     |      |
| Thermal resistance from junction to PCB       | -       | 25      | -       | °C/W |
| Thermal resistance from junction to case      | -       | 1       | -       |      |

## PIN CONFIGURATION



**Fig. 2 - Pin Configuration for SiP2204**

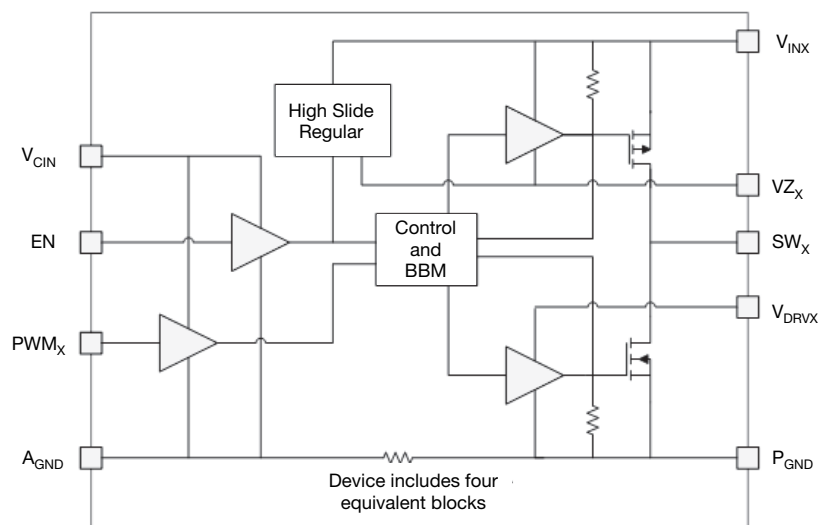
| PIN CONFIGURATION         |              |                                                                                 |
|---------------------------|--------------|---------------------------------------------------------------------------------|
| PIN NUMBER                | PIN NAME     | PIN DESCRIPTION                                                                 |
| 1, 2                      | SW 2         | Channel 2 driver output                                                         |
| 3 to 6,<br>13, 14, 27, 28 | $P_{GND}$    | Low-side driver power return for all channels                                   |
| 7, 8                      | SW 3         | Channel 3 driver output                                                         |
| 9, 10                     | $V_{IN} 34$  | Power stage input voltage and high-side driver power supply for channel 3 and 4 |
| 11, 12                    | SW 4         | Channel 4 driver output                                                         |
| 15                        | $V_{DRV} 34$ | Low-side driver power supply for channel 3 and 4                                |
| 16                        | $V_Z 34$     | High-side regulator output monitor for channel 3 and 4                          |
| 18                        | EN           | Global enable pin. Active high                                                  |
| 19                        | PWM 4        | Channel 4 PWM input (In phase with SW)                                          |
| 20                        | PWM 3        | Channel 3 PWM input (In phase with SW)                                          |
| 21                        | PWM 2        | Channel 2 PWM input (In phase with SW)                                          |
| 22                        | PWM 1        | Channel 1 PWM input (In phase with SW)                                          |
| 23                        | $V_{CIN}$    | Supply voltage for internal logic circuitry                                     |
| 17, 24, 33                | $A_{GND}$    | Analog ground                                                                   |
| 25                        | $V_Z 12$     | High-side regulator output monitor for channel 1 and 2                          |
| 26                        | $V_{DRV} 12$ | Low-side driver power supply for channel 1 and 2                                |
| 29, 30                    | SW 1         | Channel 1 driver output                                                         |
| 31, 32                    | $V_{IN} 12$  | Power stage input voltage and high-side driver power supply for channel 1 and 2 |



| ELECTRICAL SPECIFICATIONS                                                   |                                       |                                                                                                                                                                                                                                                              |                                                                         |      |      |      |
|-----------------------------------------------------------------------------|---------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------|------|------|------|
| PARAMETER                                                                   | SYMBOL                                | TEST CONDITION<br>UNLESS OTHERWISE SPECIFIED<br>V <sub>DRVX</sub> = V <sub>CIN</sub> = EN = 5 V, V <sub>INX</sub> = 15 V,<br>V <sub>INX</sub> - V <sub>ZX</sub> = 5 V, no load,<br>PWM rise and fall time = 2 ns<br>T <sub>A</sub> = 25 °C for typical value | JUNCTION TEMPERATURE<br>-40 °C to +125 °C<br>unless otherwise specified |      |      | UNIT |
|                                                                             |                                       |                                                                                                                                                                                                                                                              | MIN.                                                                    | TYP. | MAX. |      |
| POWER SUPPLY                                                                |                                       |                                                                                                                                                                                                                                                              |                                                                         |      |      |      |
| Power stage input and high-side driver supply current                       | I <sub>VIN</sub>                      | EN = 0 V, PWM <sub>X</sub> = 0 V                                                                                                                                                                                                                             | -                                                                       | -    | 1    | μA   |
|                                                                             |                                       | PWM <sub>X</sub> = 0 V                                                                                                                                                                                                                                       | -                                                                       | 90   | 130  |      |
|                                                                             |                                       | PWM <sub>X</sub> = 3.3 V (80K pull-up on high-side gate)                                                                                                                                                                                                     | -                                                                       | 230  | 330  |      |
|                                                                             |                                       | f <sub>sw</sub> = 4 MHz,<br>D = 10 %, one channel                                                                                                                                                                                                            | -                                                                       | 14   | 27.5 | mA   |
| Control logic and low-side driver supply current                            | I <sub>VCIN</sub> + I <sub>VDRV</sub> | EN = 0 V, no switching, PWM = 0                                                                                                                                                                                                                              | -                                                                       | -    | 1    | μA   |
|                                                                             |                                       | PWM <sub>X</sub> = 0 V (80K pull-down on low-side gate)                                                                                                                                                                                                      | -                                                                       | 370  | 530  |      |
|                                                                             |                                       | PWM <sub>X</sub> = 3.3 V                                                                                                                                                                                                                                     | -                                                                       | 90   | 130  |      |
|                                                                             |                                       | f <sub>sw</sub> = 4 MHz,<br>D = 10 %, one channel                                                                                                                                                                                                            | -                                                                       | 5    | 8    | mA   |
| PWM <sub>X</sub> /EN LOGIC (ALSO SEE TIMING DIAGRAM BELOW FOR ILLUSTRATION) |                                       |                                                                                                                                                                                                                                                              |                                                                         |      |      |      |
| PWM <sub>X</sub> /EN rising threshold                                       | V <sub>TH_R</sub>                     |                                                                                                                                                                                                                                                              | 2.4                                                                     | -    | -    | V    |
| PWM <sub>X</sub> /EN falling threshold                                      | V <sub>TH_F</sub>                     |                                                                                                                                                                                                                                                              | -                                                                       | -    | 0.8  |      |
| PWM <sub>X</sub> supply current                                             | I <sub>PWM</sub>                      | PWM <sub>X</sub> = 5 V                                                                                                                                                                                                                                       | -                                                                       | -    | 1    | μA   |
| EN supply current                                                           | I <sub>EN</sub>                       | R <sub>EN</sub> = 1 MΩ to AGND                                                                                                                                                                                                                               | -                                                                       | -    | 8    |      |
| PWM on time <sup>(1)</sup>                                                  | t <sub>PWM_ON</sub>                   |                                                                                                                                                                                                                                                              | 12                                                                      | -    | -    | ns   |
| PWM rising propagation delay                                                | t <sub>PD_R_PWM</sub>                 | From PWM rises to 1.7 V to SW rises to 1.5 V; 25 °C                                                                                                                                                                                                          | 8                                                                       | 15   | 22   |      |
|                                                                             |                                       | From PWM rises to 1.7 V to SW rises to 1.5 V                                                                                                                                                                                                                 | -                                                                       | -    | 25   |      |
| PWM falling propagation delay                                               | t <sub>PD_F_PWM</sub>                 | From PWM falls to 1.7 V to SW falls to 1.5 V; 25 °C                                                                                                                                                                                                          | 7                                                                       | 18   | 26   |      |
|                                                                             |                                       | From PWM falls to 1.7 V to SW falls to 1.5 V                                                                                                                                                                                                                 | -                                                                       | -    | 30   |      |
| PWM propagation delay matching <sup>(2)</sup>                               | t <sub>PD_M_PWM</sub>                 | From PWM rises to 1.7 V to SW rises to 1.5 V; 25 °C                                                                                                                                                                                                          | -                                                                       | 0.4  | 0.75 |      |
|                                                                             |                                       | From PWM rises to 1.7 V to SW rises to 1.5 V                                                                                                                                                                                                                 | -                                                                       | -    | 1    |      |
| EN propagation delay                                                        | t <sub>PD_EN</sub>                    | From EN rise to V <sub>CIN</sub> to SW start switching                                                                                                                                                                                                       | -                                                                       | 5    | -    | μs   |
| OUTPUT DRIVER                                                               |                                       |                                                                                                                                                                                                                                                              |                                                                         |      |      |      |
| Low-side on resistance                                                      | R <sub>DS(on)_N</sub>                 | I <sub>sw</sub> = 0.1 A                                                                                                                                                                                                                                      | -                                                                       | 0.35 | 0.56 | Ω    |
| High-side on resistance                                                     | R <sub>DS(on)_P</sub>                 | I <sub>sw</sub> = 0.1 A, V <sub>IN</sub> - V <sub>Z</sub> = 5 V                                                                                                                                                                                              | -                                                                       | 0.55 | 0.92 |      |

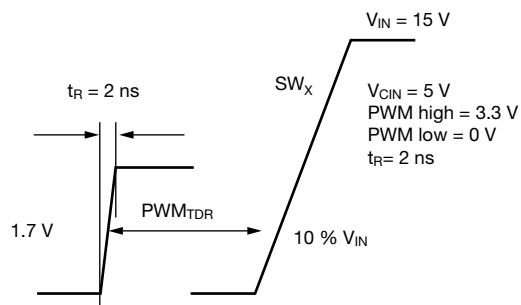
**Notes**

- (1) Guaranteed by design  
 (2) Difference between the maximum and minimum PWM propagation delay among 4 channels

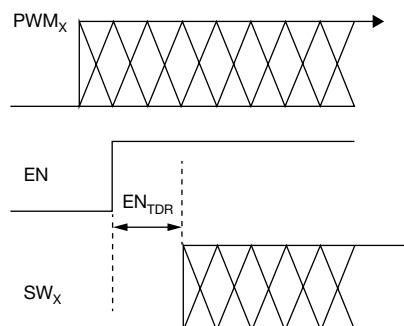
**FUNCTIONAL BLOCK DIAGRAM**

**Fig. 3 - Functional Block Diagram for SiP2204**

| ORDERING INFORMATION |                 |                          |
|----------------------|-----------------|--------------------------|
| PART NUMBER          | PACKAGE         | MARKING<br>(LINE 2: P/N) |
| SiP2204EMP-T1-GE4    | QFN32 5 x 5     | SiP2204                  |
| SiP2204DB            | Reference board |                          |

## TIMING WAVEFORMS



**Fig. 4 - Timing Waveform for SiP2204**



**Fig. 5 - Timing Waveform for SiP2204**

## DETAILED OPERATIONAL DESCRIPTION

## PWM Input

The PWM input receives the PWM control signal from the VR controller IC. The PWM input is designed to be compatible with standard controllers using two state logic (H and L) on the PWM output. For two state logic, the PWM input operates as follows. When PWM is driven above  $V_{TH\_PWM\_R}$  the low-side is turned off and the high-side is turned on. When PWM input is driven below  $V_{TH\_PWM\_F}$  the high-side turns off and the low-side turns on. The SiP2204 incorporates PWM voltage thresholds that is compatible with 3.3 V and 5 V logic.

### Enable (EN)

In the low state, the EN pin shuts down the device. In this state, standby current is minimized. If EN is left unconnected, an internal pull-down resistor will pull the pin to  $A_{GND}$  and shuts down the device. The EN pin is a global enable for all four channels when driven above  $V_{TH\ EN\ R}$ .

### High-Side Regulator Output Monitor (V<sub>7</sub>)

$V_Z 12$  and  $V_Z 34$  are the output monitors for the high-side regulators.  $V_{ZX}$  is regulated to 5 V below  $V_{IN}$  (typical).

### Voltage Input ( $V_{IN}$ )

The power input to the drain of the high-side power MOSFET and the high-side driver supply. This pin is connected to the high power intermediate BUS rail. An 80 k $\Omega$  resistor is connected between the high-side gate and V<sub>IN</sub>.

### Switch Node (SW<sub>x</sub>)

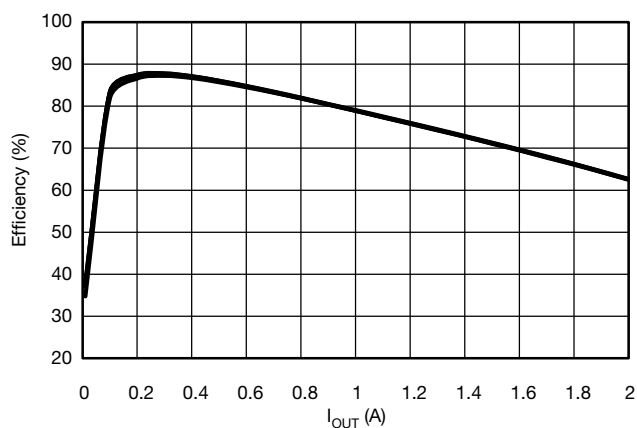
The switch node, SW, is the circuit power stage output. This is the output applied to the power inductor and output filter to deliver the output for the buck converter.

### Ground Connections ( $A_{GND}$ and $P_{GND}$ )

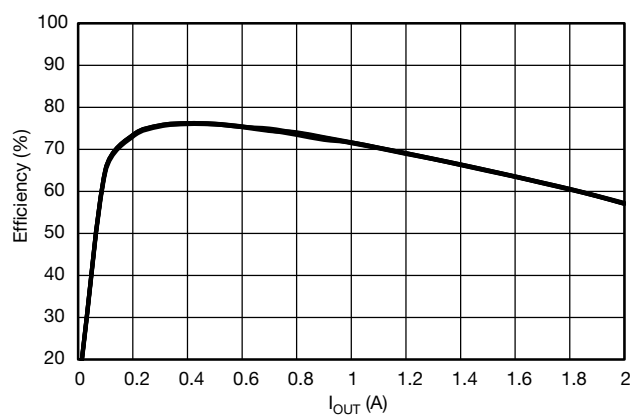
P<sub>GND</sub> (power ground) should be externally connected to A<sub>GND</sub> (analog ground). The layout of the printed circuit board should be such that the inductance separating the A<sub>GND</sub> and P<sub>GND</sub> should be a minimum. Transient differences due to inductance effects between these two pins should not exceed 0.5 V.

### Control and Drive Supply Voltage Input ( $V_{DRV}$ , $V_{GIN}$ )

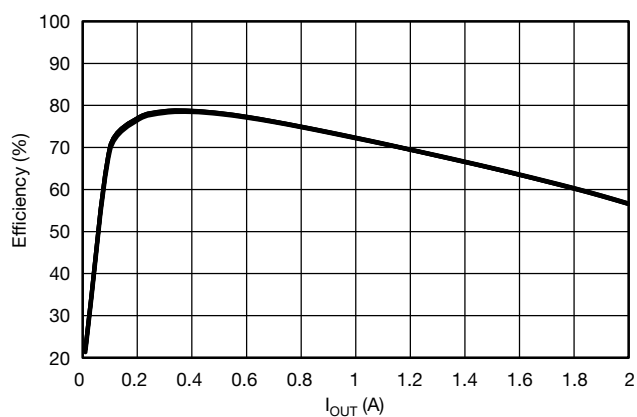
$V_{\text{CIN}}$  is the bias supply for the logic control circuitry of the IC.  $V_{\text{DRVx}}$  is the bias supply for the low-side gate drivers. It is recommended to separate these pins through a resistor. This creates a low pass filtering effect to avoid coupling of high frequency gate drive noise into the logic circuitry.

**ELECTRICAL CHARACTERISTICS** ( $V_{OUT} = 2\text{ V}$ ,  $V_{CIN} = V_{DRVx} = 5\text{ V}$ ,  $L = 4.7\text{ }\mu\text{H}$ , unless otherwise noted)


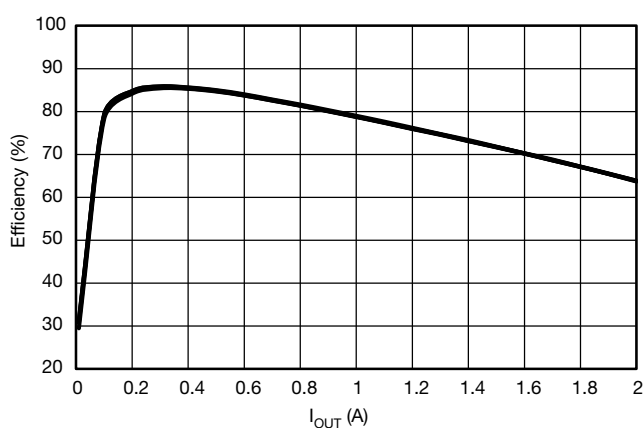
**Fig. 6 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 8\text{ V}$ ,  $f_{SW} = 1\text{ MHz}$



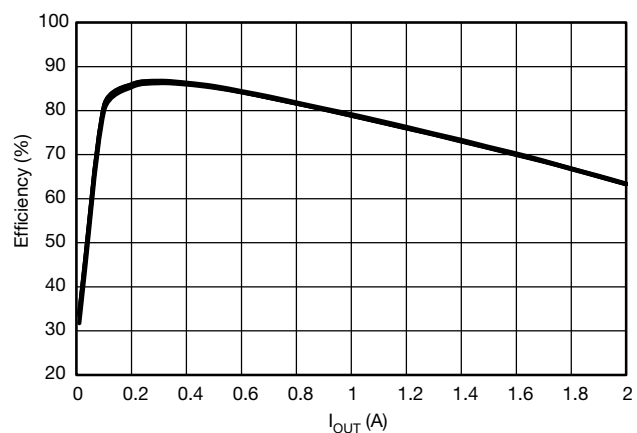
**Fig. 9 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 10\text{ V}$ ,  $f_{SW} = 5\text{ MHz}$



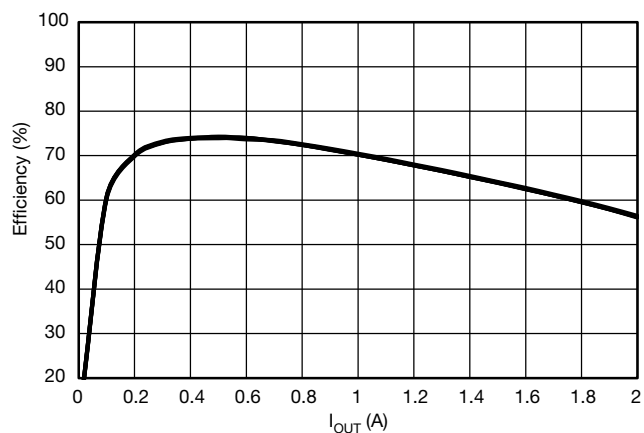
**Fig. 7 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 8\text{ V}$ ,  $f_{SW} = 5\text{ MHz}$



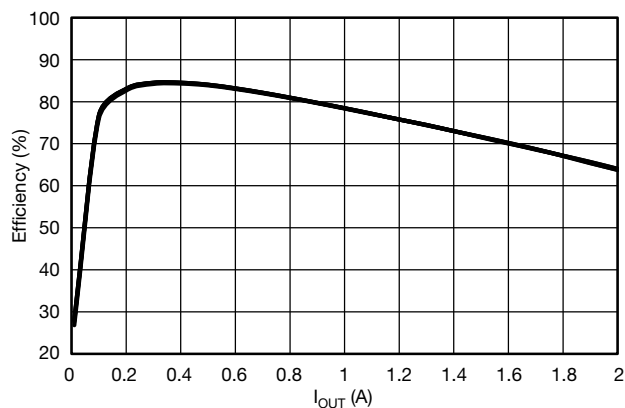
**Fig. 10 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 1\text{ MHz}$



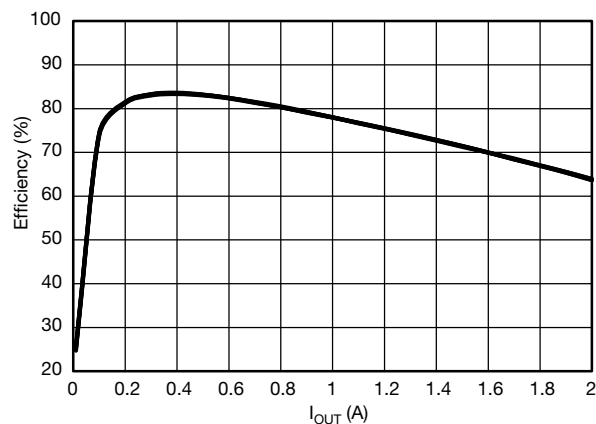
**Fig. 8 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 10\text{ V}$ ,  $f_{SW} = 1\text{ MHz}$



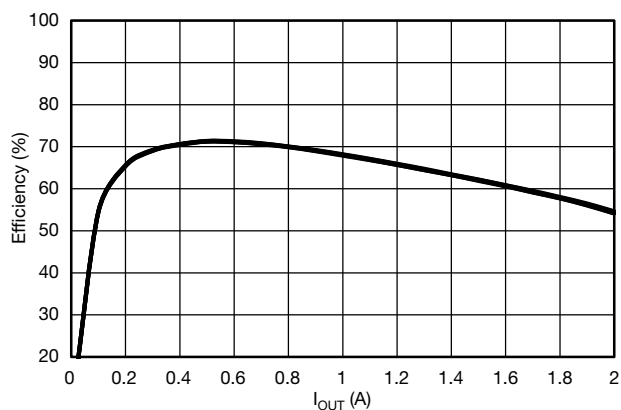
**Fig. 11 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 5\text{ MHz}$

**ELECTRICAL CHARACTERISTICS** ( $V_{OUT} = 2\text{ V}$ ,  $V_{CIN} = V_{DRVx} = 5\text{ V}$ ,  $L = 4.7\text{ }\mu\text{H}$ , unless otherwise noted)


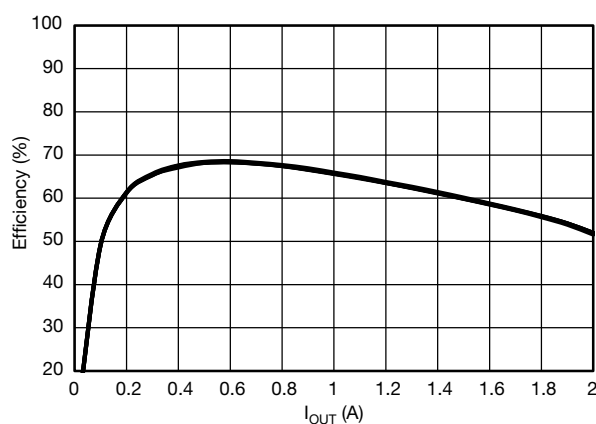
**Fig. 12 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 15\text{ V}$ ,  $f_{SW} = 1\text{ MHz}$



**Fig. 14 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 18\text{ V}$ ,  $f_{SW} = 1\text{ MHz}$



**Fig. 13 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 15\text{ V}$ ,  $f_{SW} = 5\text{ MHz}$

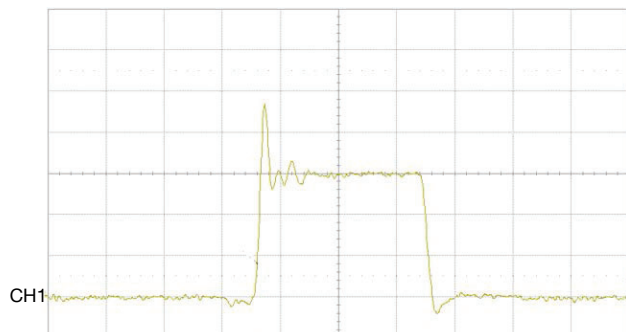


**Fig. 15 - Efficiency vs.  $I_{OUT}$**   
 $V_{IN} = 18\text{ V}$ ,  $f_{SW} = 5\text{ MHz}$

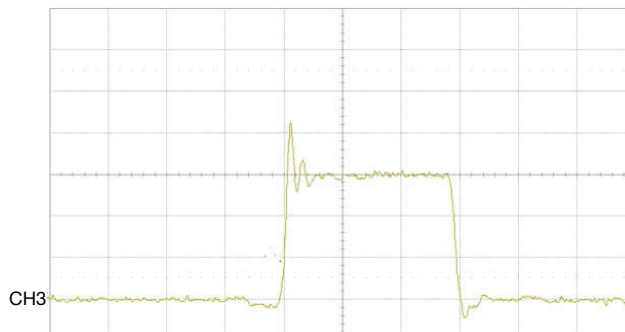


# ELECTRICAL CHARACTERISTICS

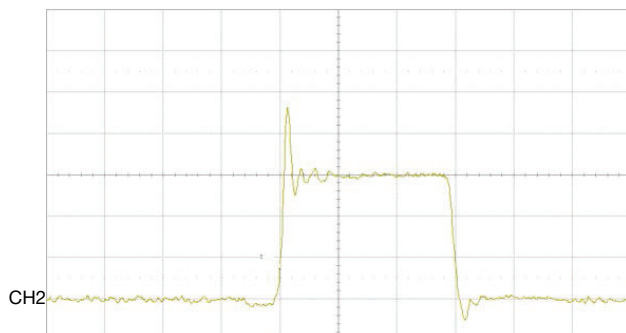
( $V_{IN} = 15\text{ V}$ ,  $V_{OUT} = 2\text{ V}$ ,  $V_{CIN} = V_{DRVx} = 5\text{ V}$ ,  $I_{OUT} = 0.5\text{ A}$ ,  $f_{SW} = 5\text{ MHz}$ ,  $L = 4.7\text{ }\mu\text{H}$ , unless otherwise noted)



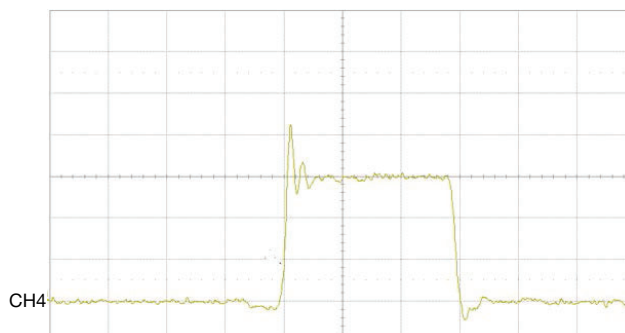
**Fig. 16 - Output Switching Waveform**  
CH1 (YLLW) = SW1 (5 V/div.), Time = 10 ns/div.



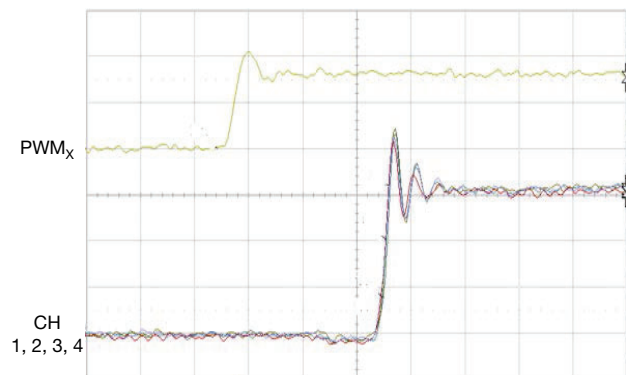
**Fig. 19 - Output Switching Waveform**  
CH3 (YLLW) = SW3 (5 V/div.), Time = 10 ns/div.



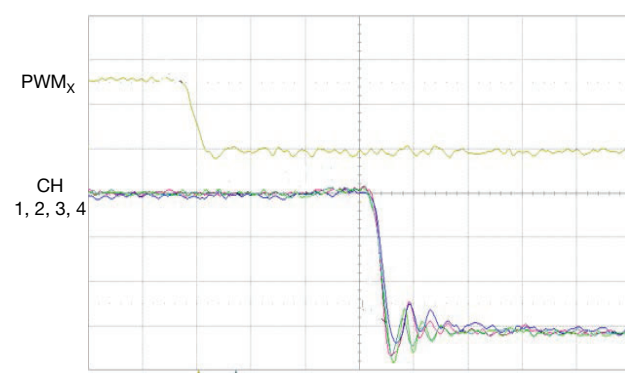
**Fig. 17 - Output Switching Waveform**  
CH2 (YLLW) = SW2 (5 V/div.), Time = 10 ns/div.



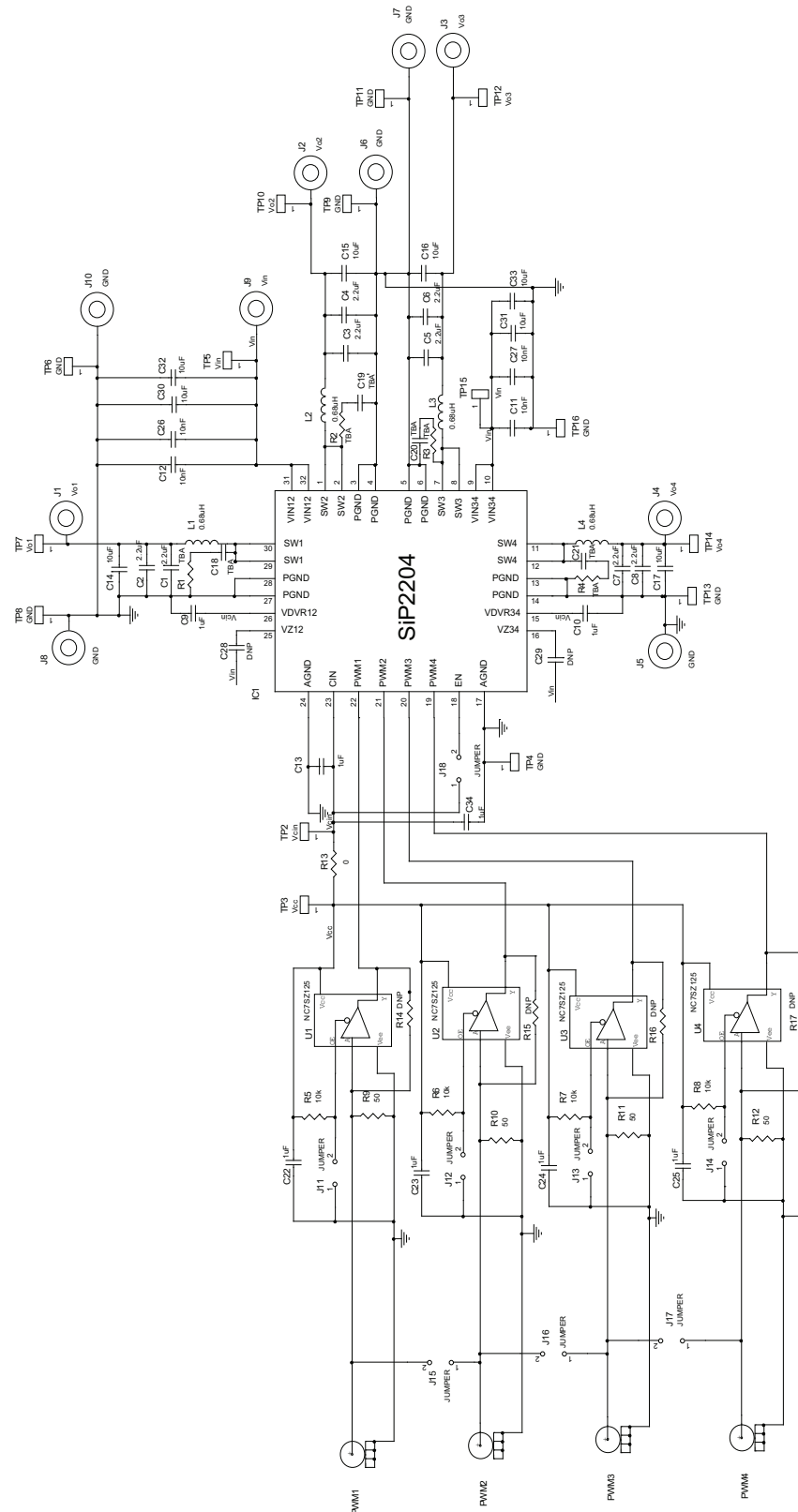
**Fig. 20 - Output Switching Waveform**  
CH4 (YLLW) = SW4 (5 V/div.), Time = 10 ns/div.



**Fig. 18 - Propagation Delay - Rising (all channels)**  
CH1 = (VLT) = SW1 (5 V/div.), CH2 = (RED) = SW2 (5 V/div.),  
CH3 = (BLU) = SW3 (5 V/div.), CH4 = (GRN) = SW4 (5 V/div.),  
PWM<sub>x</sub> (YLLW) = 2 V/div., Time = 5 ns/div.

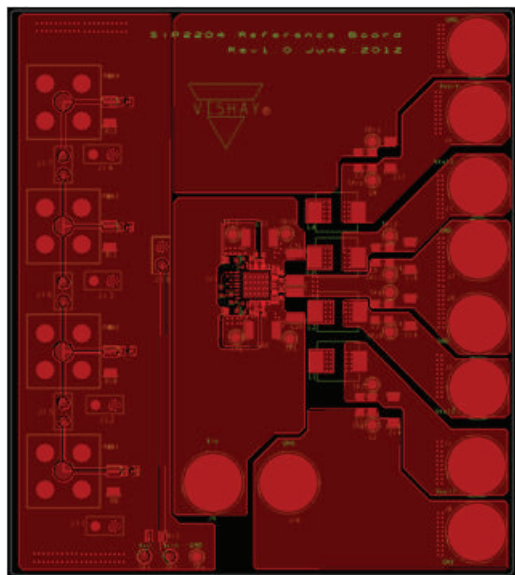
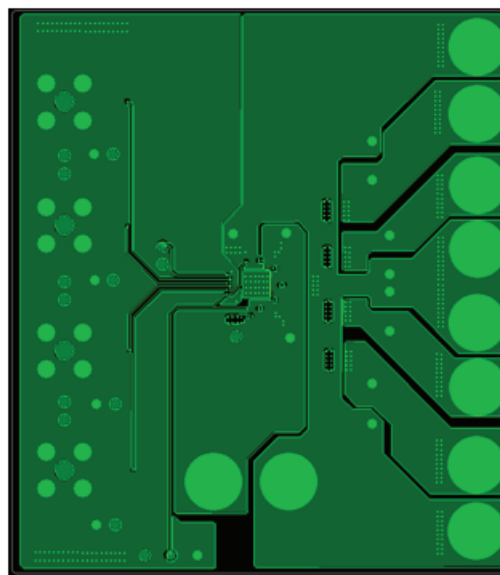
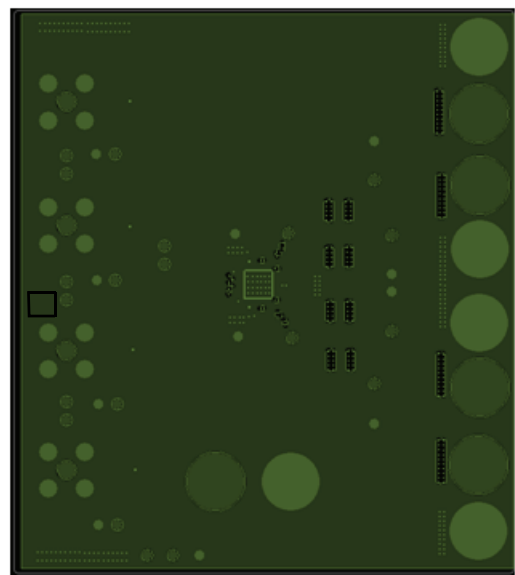
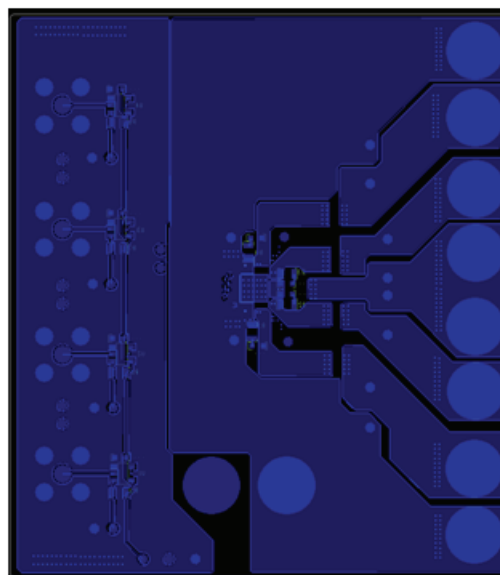


**Fig. 21 - Propagation Delay - Falling (all channels)**  
CH1 = (VLT) = SW1 (5 V/div.), CH2 = (RED) = SW2 (5 V/div.),  
CH3 = (BLU) = SW3 (5 V/div.), CH4 = (GRN) = SW4 (5 V/div.),  
PWM<sub>x</sub> (YLLW) = 2 V/div., Time = 5 ns/div.

**DEMO BOARD SCHEMATIC**

**Fig. 22 - Reference Board Schematic for SiP2204**

**BILL OF MATERIALS**

| ITEM | QTY. | REFERENCE                              | COMPONENT VALUE    | PCB FOOTPRINT |
|------|------|----------------------------------------|--------------------|---------------|
| 1    | 8    | C1, C2, C3, C4, C5, C6, C7, C8         | 2.2 $\mu$ F, 6.3 V | 0805          |
| 2    | 4    | C9, C10, C13, C34                      | 1 $\mu$ F, 6.3 V   | 0402          |
| 3    | 4    | C11, C12, C26, C27                     | 10 nF, 25 V        | 0805          |
| 4    | 4    | C14, C15, C16, C17                     | 10 $\mu$ F, 6.3 V  | 1206          |
| 5    | 4    | C18, C19, C20, C21                     | DNP                | 0603          |
| 6    | 4    | C22, C23, C24, C25                     | 1 $\mu$ F, 10 V    | 0603          |
| 7    | 2    | C28, C29                               | DNP                | 0603          |
| 8    | 4    | C30, C31, C32, C33                     | 10 $\mu$ F, 25 V   | 1210          |
| 9    | 1    | IC1                                    | SiP2204            | QFN5x5-32     |
| 10   | 1    | J1                                     | V <sub>O1</sub>    | Banana        |
| 11   | 1    | J2                                     | V <sub>O2</sub>    | Banana        |
| 12   | 1    | J3                                     | V <sub>O3</sub>    | Banana        |
| 13   | 1    | J4                                     | V <sub>O4</sub>    | Banana        |
| 14   | 5    | J5, J6, J7, J8, J10                    | GND                | Banana        |
| 15   | 1    | J9                                     | V <sub>IN</sub>    | Banana        |
| 16   | 8    | J11, J12, J13, J14, J15, J16, J17, J18 | JUMPER             | Jumper2       |
| 17   | 4    | L1, L2, L3, L4                         | 4.7 $\mu$ H        | IHLP2525A     |
| 18   | 4    | PWM1, PWM2, PWM3, PWM4                 | SMA connect        | SMA           |
| 19   | 4    | R1, R2, R3, R4                         | DNP                | R0805-Vishay  |
| 20   | 4    | R5, R6, R7, R8                         | 10 k $\Omega$      | R0805-Vishay  |
| 21   | 4    | R9, R10, R11, R12                      | 50 $\Omega$        | R1206-Vishay  |
| 22   | 1    | R13                                    | 0 $\Omega$         | R0805-Vishay  |
| 23   | 4    | R14, R15, R16, R17                     | DNP                | R0603-Vishay  |
| 24   | 1    | TP2                                    | V <sub>CIN</sub>   | TP30          |
| 25   | 1    | TP3                                    | V <sub>CC</sub>    | TP30          |
| 26   | 7    | TP4, TP6, TP8, TP9, TP11, TP13, TP16   | GND                | TP30          |
| 27   | 2    | TP5, TP15                              | V <sub>IN</sub>    | TP30          |
| 28   | 1    | TP7                                    | V <sub>O1</sub>    | TP30          |
| 29   | 1    | TP10                                   | V <sub>O2</sub>    | TP30          |
| 30   | 1    | TP12                                   | V <sub>O3</sub>    | TP30          |
| 31   | 1    | TP14                                   | V <sub>O4</sub>    | TP30          |
| 32   | 4    | U1, U2, U3, U4                         | NC7SZ125           | SOT23-5       |

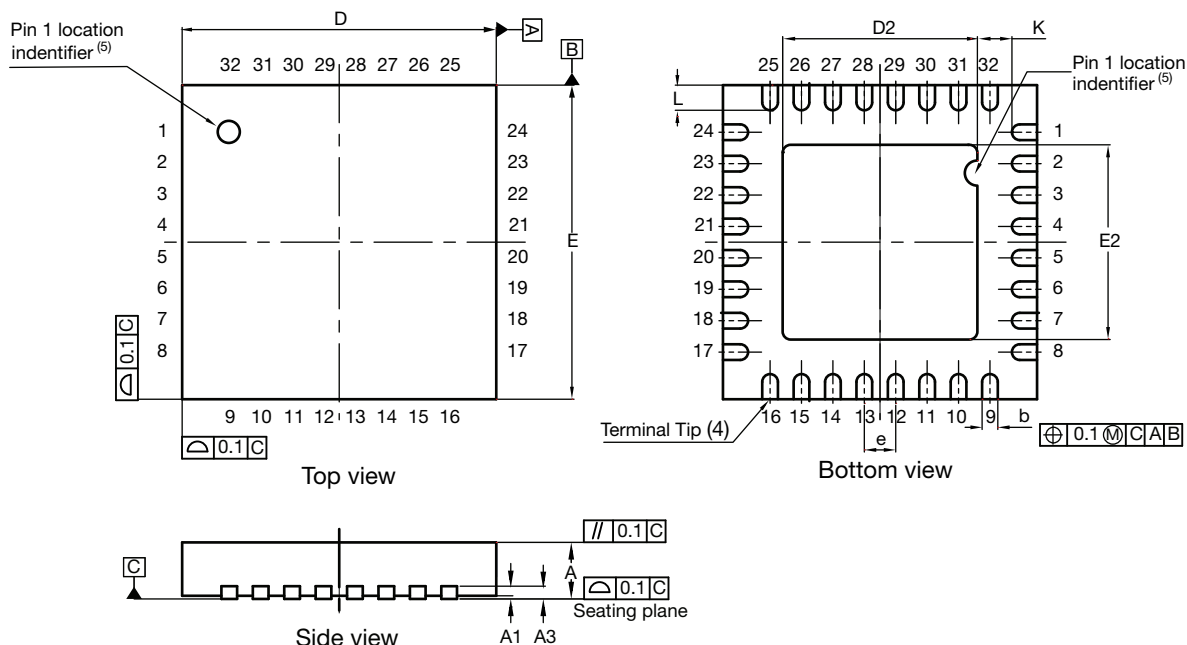
**PCB LAYOUT OF REFERENCE BOARD**

**Fig. 23 - Top Layer**

**Fig. 25 - Inner 2**

**Fig. 24 - Inner 1**

**Fig. 26 - Bottom**



| PRODUCT SUMMARY                    |                                                                                               |
|------------------------------------|-----------------------------------------------------------------------------------------------|
| Part number                        | SiP2204                                                                                       |
| Description                        | 0.5 A power stage, 10 V <sub>IN</sub> to 24 V <sub>IN</sub> , 3.3 V and 5.5 V PWM with - mode |
| Input voltage min. (V)             | 10                                                                                            |
| Input voltage max. (V)             | 24                                                                                            |
| Continuous current rating max. (A) | 0.5                                                                                           |
| Switch frequency max. (kHz)        | 5000                                                                                          |
| Enable (yes / no)                  | YES                                                                                           |
| Monitoring features                | -                                                                                             |
| Protection                         | UVLO                                                                                          |
| Light load mode                    | -                                                                                             |
| Pulse-width modulation (V)         | 3.3 and 5                                                                                     |
| Package type                       | QFN32-55                                                                                      |
| Package size (W, L, H) (mm)        | 5.0 x 5.0 x 0.85                                                                              |
| Status code                        | 2                                                                                             |
| Product type                       | VRPower (DrMOS)                                                                               |
| Applications                       | Computer, industrial, networking                                                              |

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## QFN32 5 x 5 Case Outline



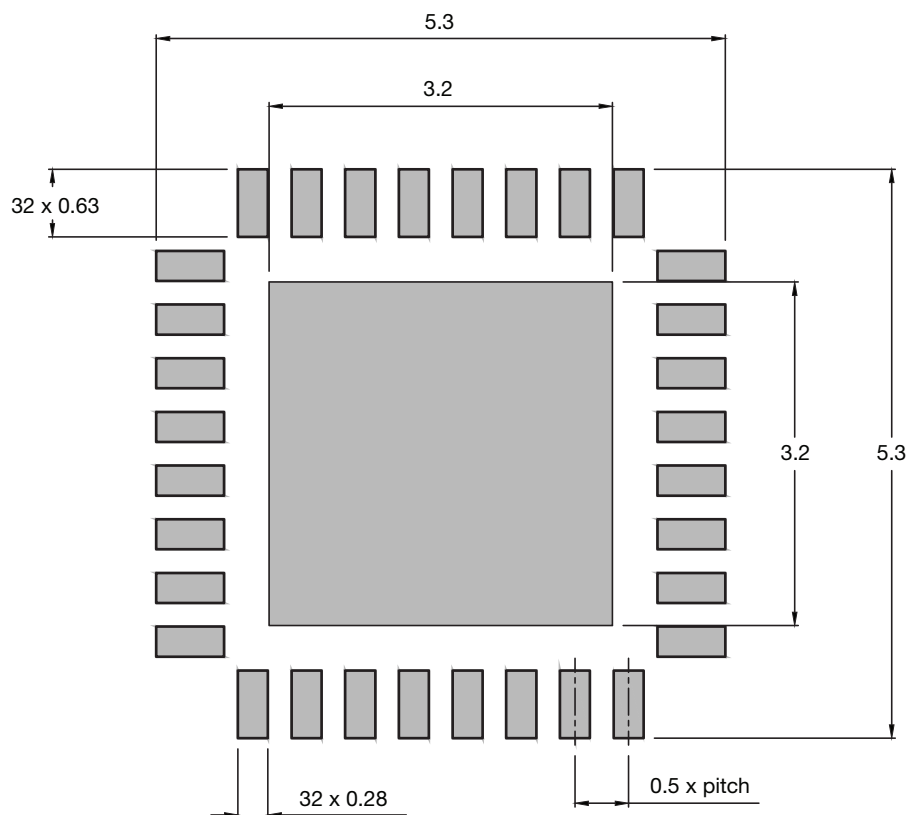
| DIM.              | MILLIMETERS |      |      | INCHES     |       |       |
|-------------------|-------------|------|------|------------|-------|-------|
|                   | MIN.        | NOM. | MAX. | MIN.       | NOM.  | MAX.  |
| A                 | 0.75        | 0.85 | 0.95 | 0.029      | 0.033 | 0.037 |
| A1                | 0.00        | -    | 0.05 | 0.000      | -     | 0.002 |
| A3                | 0.20 ref.   |      |      | 0.008 ref. |       |       |
| b                 | 0.18        | 0.25 | 0.30 | 0.007      | 0.010 | 0.012 |
| D                 | 5.00 BSC    |      |      | 0.197 BSC  |       |       |
| D2                | 3.00        | 3.10 | 3.20 | 0.118      | 0.122 | 0.126 |
| e                 | 0.50 BSC    |      |      | 0.020 BSC  |       |       |
| E                 | 5.00 BSC    |      |      | 0.197 BSC  |       |       |
| E2                | 3.00        | 3.10 | 3.20 | 0.118      | 0.122 | 0.126 |
| K                 | 0.20        | -    | -    | 0.008      | -     | -     |
| L                 | 0.30        | 0.40 | 0.50 | 0.012      | 0.016 | 0.020 |
| N <sup>(3)</sup>  | 32          |      |      | 32         |       |       |
| Nd <sup>(3)</sup> | 8           |      |      | 8          |       |       |
| Ne <sup>(3)</sup> | 8           |      |      | 8          |       |       |

### Notes

- (1) Use millimeters as the primary measurement
- (2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994
- (3) N is the number of terminals,  
Nd is the number of terminals in X-direction and  
Ne is the number of terminals in Y-direction.
- (4) Dimension b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip
- (5) The pin #1 identifier must be existed on the top surface of the package by using indentation mark or other feature of package body
- (6) Package warpage max. 0.05 mm

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## Recommended Land Pattern QFN32 5 x 5



Dimensions are in millimeters



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